

CY14B116N-BA25XI

CY14B116N-BA25XI Information

Containance container		CY14B116N-BA25XI Cypress Semiconductor Corp Integrated Circuits (ICs) Memory NON VOLATILE SRAMS - For the pricing/inventory/lead time, please contact	
For Reference Only	у	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



CY14B116N-BA25XI Specifications

Manufacturer Part Number	CY14B116N-BA25XI
Manufacturer	Cypress Semiconductor Corp
Category	Integrated Circuits (ICs)
	Memory
Package	-
Series	-
Memory Type	Non-Volatile
Memory Format	NVSRAM
Technology	NVSRAM (Non-Volatile SRAM)
Memory Size	16Mb (1M x 16)
Memory Interface	Parallel
Clock Frequency	-
Write Cycle Time - Word, Page	25ns
Access Time	25ns
Voltage - Supply	2.7 V ~ 3.6 V
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	-
Package / Case	-
Supplier Device Package	-
	Report errors?

CY14B116N-BA25XI Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

CY14B116N-BA25XI Payment Methods





If you have any question about CY14B116N-BA25XI, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com